



DMG7401SFGQ

P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C		
001/	$13m\Omega$ @ $V_{GS} = -10V$	-9.8A		
-30V	$25m\Omega$ @ $V_{GS} = -4.5V$	-7.0A		

Description

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

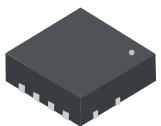
- Low R_{DS(ON)} Ensures On-State Losses Are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of The Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

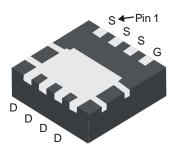
- Case: PowerDI[®] 3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0174 grams (Approximate)

PowerDI3333-8

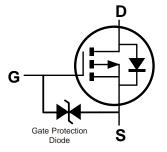








Bottom View



Equivalent Circuit

Ordering Information (Note 5)

Part Number	Case	Packaging
DMG7401SFGQ-7	PowerDI3333-8	2,000/Tape & Reel
DMG7401SFGQ-13	PowerDI3333-8	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/



Marking Information



G75 = Product Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 for 2018) WW = Week Code (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V_{DSS}	-30	V
Gate-Source Voltage			V_{GSS}	±25	V
Continuous Drain Current (Note 7) / 10\/	Steady State	$T_A = +25$ °C $T_A = +70$ °C	I _D	-9.8 -7.7	А
Continuous Drain Current (Note 7) V _{GS} = -10V	t<10s	$T_A = +25$ °C $T_A = +70$ °C	I _D	-13.5 -10.8	А
Maximum Continuous Body Diode Forward Current	I _S	-3.0	Α		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	-80	Α
Avalanche Current (Notes 8 & 9)			I _{AR}	-14	Α
Repetitive Avalanche Energy (Notes 8 & 9) L = 1m	E _{AR}	104	mJ		

Thermal Characteristics

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	C	0.94	W	
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	P_{D}	0.6		
Thermal Pasistance, Junation to Ambient (Note 6)	Steady State	D	137	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	82	°C/W	
Total Power Dissipation (Note 7)	$T_A = +25$ °C	c -	2.2	W	
Total Power Dissipation (Note 7)	$T_A = +70^{\circ}C$	P _D	1.3	Į vv	
Thermal Begistenes, Junetian to Ambient (Note 7)	Steady State	ם	60	°C/W	
Thermal Resistance, Junction to Ambient (Note 7)	t<10s	$R_{\theta JA}$	36	°C/W	
Thermal Resistance, Junction to Case (Note 7)		$R_{ heta JC}$	3.0	°C/W	
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C	

Notes:

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.
- 8. I_{AR} and E_{AR} ratings are based on low frequency and duty cycles to keep $T_{J} = +25$ °C.



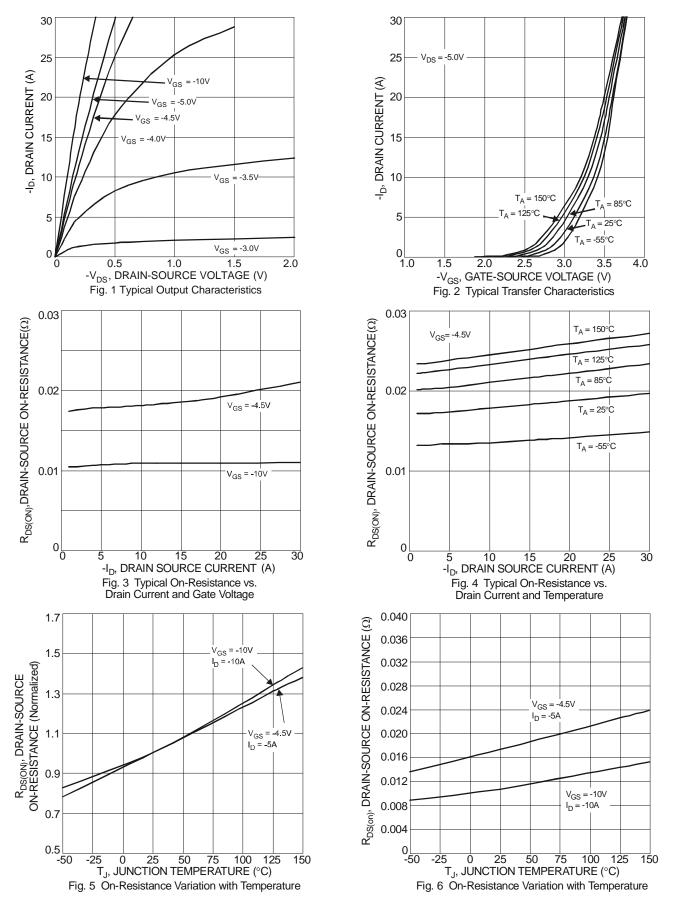
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}		_	-1	μΑ	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(TH)}	-1.7	_	-3.0	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
			9	11		$V_{GS} = -20V, I_D = -12A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	10	13	$m\Omega$	$V_{GS} = -10V, I_{D} = -9A$	
		1	17	25		$V_{GS} = -4.5V, I_D = -5A$	
Forward Transfer Admittance	Y _{fs}	l	21	_	S	$V_{DS} = -5V, I_{D} = -10A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	l	2,246	2,987	рF	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	
Output Capacitance	Coss	l	352	468	рF	$V_{DS} = -15V, V_{GS} = 0V,$ -f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	-	294	391	рF	T = 1.0IVII IZ	
Gate Resistance	R_{g}	l	5.1	10	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Q_g	l	20.5	30	nC		
Total Gate Charge (V _{GS} = -10V)	Q_g	l	41	58	nC	V _{DS} = -15V. I _D = -12A	
Gate-Source Charge	Q_{gs}	l	7.6		nC	$V_{DS} = -15V, I_{D} = -12A$	
Gate-Drain Charge	Q_{gd}	l	8.0		nC		
Turn-On Delay Time	t _{D(ON)}	_	11.3	23	ns		
Turn-On Rise Time	t _R	_	15.4	31	ns	$V_{DD} = -15V, V_{GS} = -10V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	38.0	61	ns	$R_L = 1.25\Omega$, $R_G = 3\Omega$	
Turn-Off Fall Time	t _F	_	22.0	38	ns		
BODY DIODE CHARACTERISTICS							
Diode Forward Voltage	V_{SD}	_	-0.7	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
Reverse Recovery Time (Note 10)	t _{RR}	_	20	31	ns	1- 0.50 dl/dt 1000/:	
Reverse Recovery Charge (Note 10)	Q _{RR}	I	9.5	18	nC	$I_S = -9.5A$, $dI/dt = 100A/\mu s$	

^{9.} Short duration pulse test used to minimize self-heating effect. 10. Guaranteed by design. Not subject to product testing.









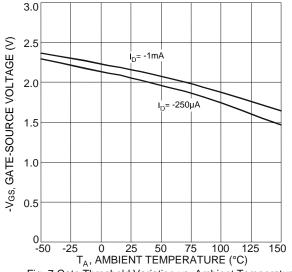
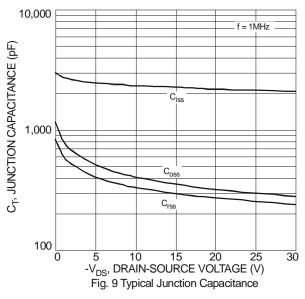
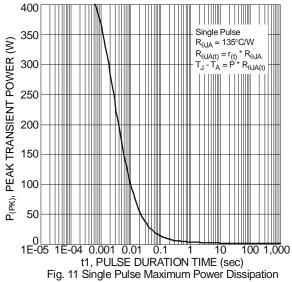
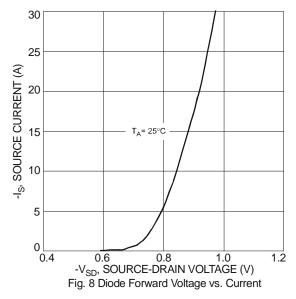
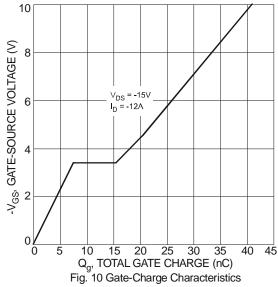


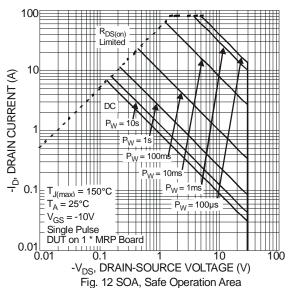
Fig. 7 Gate Threshold Variation vs. Ambient Temperature



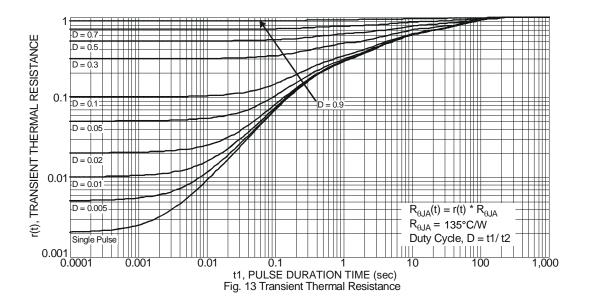










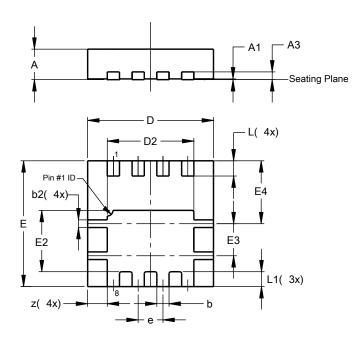




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

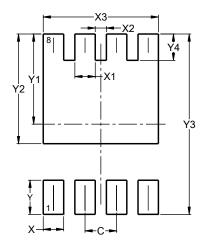


PowerDI3333-8						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	-	_	0.203			
b	0.27	0.37	0.32			
b2	0.15	0.25	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
Е	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
E3	0.79	0.89	0.84			
E4	1.60	1.70	1.65			
е	_	_	0.65			
L	0.35	0.45	0.40			
L1	_	_	0.39			
Z	_	_	0.515			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
٧a	0.540



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